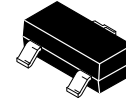


NPN General Purpose Amplifier

BCW71



SOT-23
CASE 318

Description

This device is designed for general purpose amplifier applications at collector currents to 300 mA. Sourced from Process 10.

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted.) (Notes 1, 2)

Symbol	Parameter	Value	Unit
V_{CEO}	Collector–Emitter Voltage	45	V
V_{CBO}	Collector–Base Voltage	50	V
V_{EBO}	Emitter–Base Voltage	5.0	V
I_C	Collector Current – Continuous	500	mA
T_J, T_{STG}	Operating and Storage Junction Temperature Range	–55 to +150	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- These ratings are based on a maximum junction temperature of 150°C .
- These are steady–state limits. **onsemi** should be consulted on applications involving pulsed or low–duty–cycle operations.

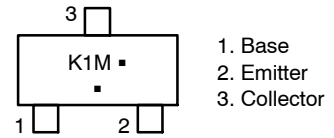
THERMAL CHARACTERISTICS

($T_A = 25^\circ\text{C}$ unless otherwise noted.) (Note 3)

Symbol	Parameter	Max	Unit
P_D	Total Device Dissipation	350	mW
	Derate Above 25°C	2.8	mW/ $^\circ\text{C}$
$R_{\theta JA}$	Thermal Resistance, Junction–to–Ambient	357	$^\circ\text{C}/\text{W}$

- Device mounted on FR–4 PCB 40 mm x 40 mm x 1.5 mm.

MARKING DIAGRAM



- K1 = Specific Device Code
- M = Date Code
- = Pb–Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping
BCW71	SOT–23 (Pb–Free, Halide Free)	3,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

BCW71

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted.)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
--------	-----------	-----------------	-----	-----	-----	------

OFF CHARACTERISTICS

V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 1.0 mA, I _B = 0	45	-	-	V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 10 μA, I _E = 0	50	-	-	V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 10 μA, I _C = 0	5.0	-	-	V
I _{CBO}	Collector Cut-Off Current	V _{CB} = 20 V, I _E = 0 V _{CB} = 20 V, I _E = 0, T _A = 100°C	- -	- -	100 10	μA

ON CHARACTERISTICS

h _{FE}	DC Current Gain	I _C = 2.0 mA, V _{CE} = 5.0 V	110	-	220	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 10 mA, I _B = 0.5 mA	-	-	0.25	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 50 mA, I _B = 2.5 mA	-	0.85	-	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = 2.0 mA, V _{CE} = 5.0 V	0.6	-	0.75	V

SMALL SIGNAL CHARACTERISTICS

f _T	Current Gain - Bandwidth Product	I _C = 10 mA, V _{CE} = 5.0 V, f = 35 MHz	-	330	-	MHz
C _{obo}	Output Capacitance	V _{CE} = 10 V, I _E = 0, f = 1.0 MHz	-	-	4.0	pF
C _{ibo}	Input Capacitance	V _{EB} = 0.5 V, I _C = 0, f = 1.0 MHz	-	9.0	-	pF
NF	Noise Figure	I _C = 0.2 mA, V _{CE} = 5.0 V, R _S = 2.0 kΩ, f = 1.0 kHz, BW = 200 Hz	-	-	10	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL CHARACTERISTICS

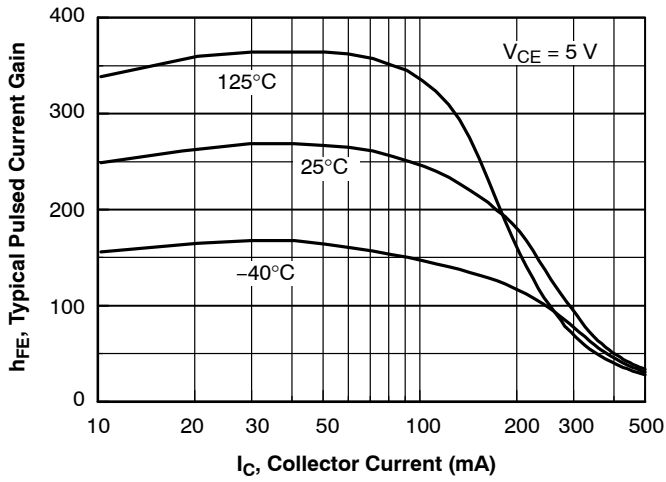


Figure 1. Typical Pulsed Current Gain vs. Collector Current

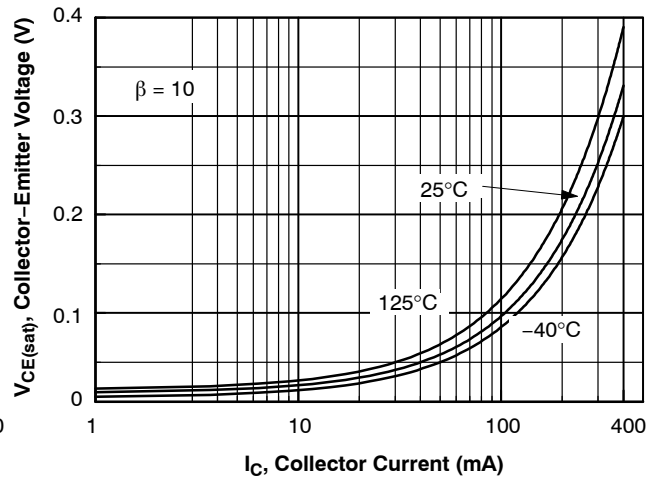


Figure 2. Collector-Emitter Saturation Voltage vs. Collector Current

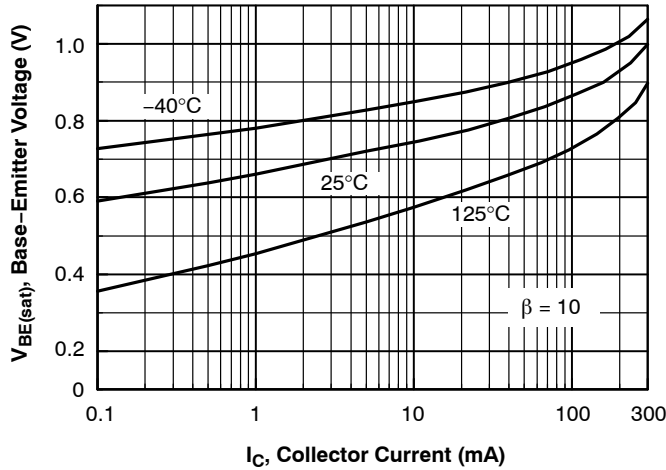


Figure 3. Base-Emitter Saturation Voltage vs. Collector Current

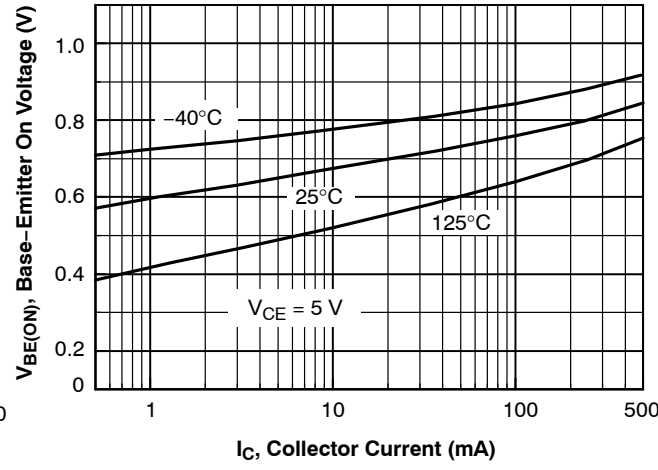


Figure 4. Base Emitter On Voltage vs. Collector Current

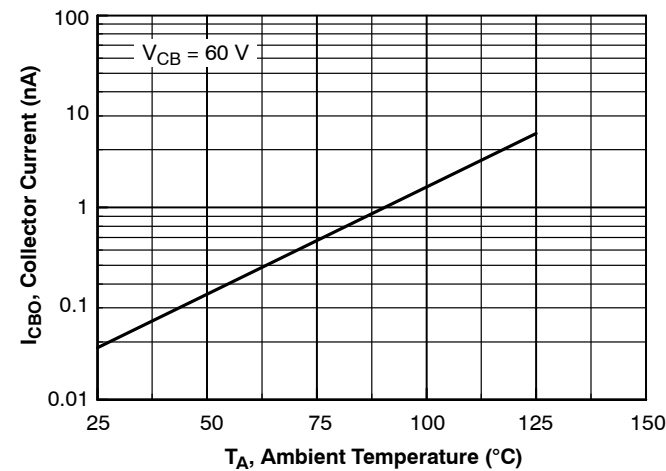


Figure 5. Collector Cut-Off Current vs. Ambient Temperature

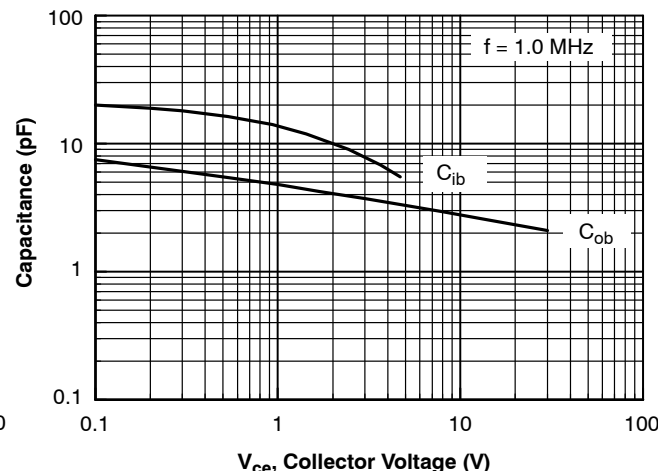


Figure 6. Input and Output Capacitance vs. Reverse Voltage

BCW71

TYPICAL CHARACTERISTICS (Continued)

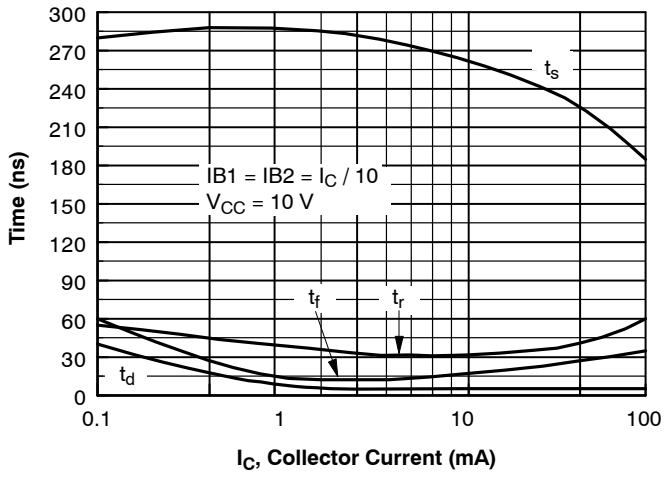


Figure 7. Switching Times vs. Collector Current

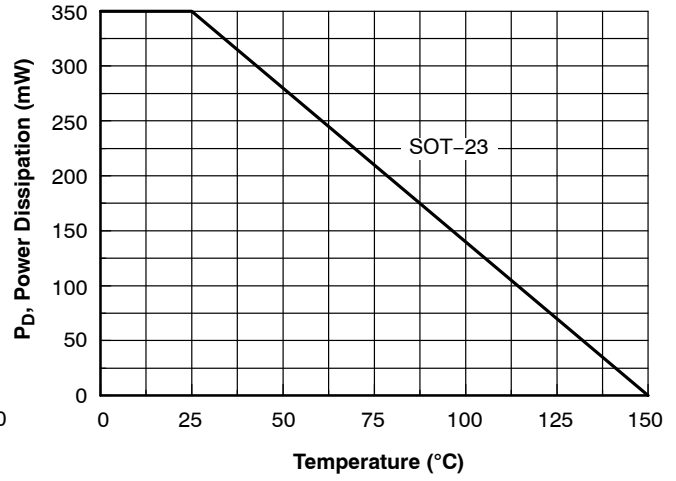


Figure 8. Power Dissipation vs. Ambient Temperature

onsemi, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation
onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at www.onsemi.com/support/sales